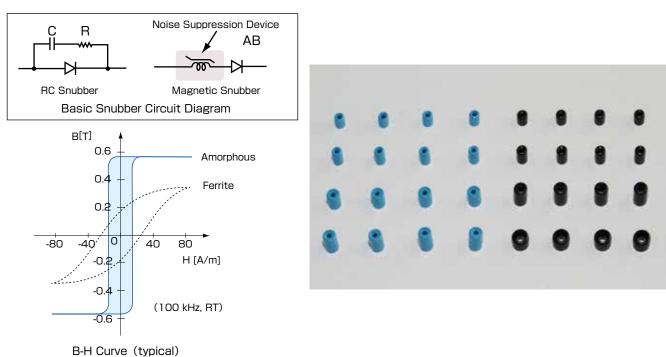
1. Noise Suppression Devices AMOBEADSTM

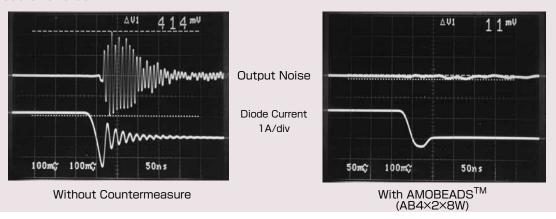
An amorphous noise suppression device is unique and completely different from conventional noise filters. Conventional noise prevention products focus on somehow minimizing the noise after it's been created, by typically trying to absorb the noise, and so their effectiveness in noise reduction is directly influenced by frequency of the circuit. Amorphous noise suppressing devices, on the other hand, focus on the source of the noise and work to prevent or minimize the noise before it has a chance to develop. The source of the electronic circuit noise is the rapid change of current or voltage, and the effectiveness of the amorphous cores in eliminating this noise is independent of frequency.

An amorphous noise suppression device is a product that takes full advantage of the unique magnetic characteristics of the cobalt based amorphous alloy. Toshiba Materials offers two noise suppression devices, "AMOBEADSTM" and "SPIKE KILLERSTM". AMOBEADSTM" deliver excellent noise suppression results and are convenient to use by simply being slipped over the leads of the semiconductor device. "AMOBEADSTM" are also available with a lead thru and in a surface mount configuration. "SPIKE KILLERSTM", which are larger in size than "AMOBEADSTM", most often are wire wound and are effective in eliminating or minimizing higher noise levels.



Example for Noise Suppressing Effect (Chopper Converter)

With an excellent saturable characteristic, "AMOBEADSTM" suppress the reverse recovery current of the diode and decrease the noise that is occurring. When the current for diode reverses and tries to go into the recovery condition, the "AMOBEADSTM" displays a large inductance and oppose the generation of the recovery current. In this instance, a soft recovery is possible for core material with a smaller coercive force.



AB/LB Series

Standard Specifications

AMOBEADS™

W series

Type No.	Finished Dimensions [mm]			Core Size [mm]*1			Total Flux*2	AL value*3	Insulating	Packing
	O.D. max	I. D. min	H.T. max	O.D.	I. D.	H.T.	φc[μWb] min	L[µH] min	Cover	Unit
AB3X2X3W	4.0	1.5	4.5	3.0	2.0	3.0	0.9	3.0		
AB3X2X4.5W	4.0	1.5	6.0	3.0	2.0	4.5	1.3	5.0		2.000
AB4X2X4.5W	5.0	1.5	6.0	4.0	2.0	4.5	2.7	9.0	PBT case Blue	[pcs/box]
AB4X2X6W	5.0	1.5	7.5	4.0	2.0	6.0	3.6	12.0	Bide	
AB4X2X8W	5.0	1.5	9.5	4.0	2.0	8.0	4.8	16.0		

DY series (low price) (Recommend for big demand, 10,000pcs/lot)

Type No.	Finished Dimer	nsions [mm]	Total Flux*7	Insulating	Packing Unit [pcs/bag]	
Type No.	O.D.	H.T.	<i>φ</i> c[<i>μ</i> Wb]	Cover		
AB2.8X4.5DY	4.0±0.2	5.7±0.3	0.9min	PBT Black	10,000	
AB3X2X3DY	4.0±0.2	4.2±0.3	0.9min	PBT Black	10,000	
AB3X2X4.5DY	4.0±0.2	5.7±0.3	1.3min	PBT Gray	10,000	
AB4X2X6DY	5.0+0.2/-0.3	7.2±0.3	3.6min	PBT Black	5,000	
AB5X4X3DY	5.95±0.2	4.2±0.3	0.45min	PBT Black	5,000	

^{*}Inner diameter can pass through a 1.2X0.7mm lead. However, Inner diameter of AB5x4x3DY can pass through a 2.5x0.7 mm lead.

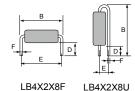


W series DY sereis

AMOBEADS™ with lead

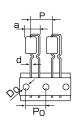
Bulk type

Tune Ne	Fi	nished Dir	mensions (r	mm]	*4 Current	*2 Total flux	AL Value	Insulating	Packing
Type No.	В	D	E	F	[A]	φc[μWb]	L[µH]	Cover	Unit
LB4X2X8F	16.0max	4.2±0.5	14.0±1.0	φ1.25±0.1	(8.0)	4.8	16.0	PBT case	1,000
LB4X2X8U	20.0max	4.0±0.5	5.0±1.0	φ1.25±0.1	(6.0)	min	min	Black	[pcs/box]



Radial taping

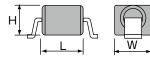
Type No.	P [mm]	Po [mm]	Do [mm]	a [mm]	d [mm]	Current*4 I [A]	Total Flux* ⁷ φc[μWb]	Packing Unit
LB2.8X4.5U	12.7	12.7	φ4.0	9.0max	φ0.8	(5)	0.9min	3,000 [pcs/box]



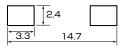
SMD Type AMOBEADS™

Type No.	Finished Dimensions [mm]			Lead	lo *4	Total Flux	AL value	Insulating	Packing Unit
Type No.	width	length	height	width x thickness	[A]	ϕ c[μ Wb]	L[µH]	Cover	[pcs/reel]
AB3X2X3SM	5.0±0.3	5.0±0.3	4.0±0.3	(1.8×0.35)	(6.0)	0.9 min	3.0	LCP case	2,000
AB4X2X6SM	6.0±0.3	8.0±0.3	5.0±0.3	(1.8×0.52)	(9.0)	3.6 min	12.0	Black	1,000

Recommended Land Pattern (mm)







AB4X2X6SM

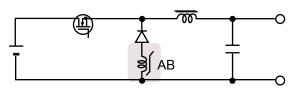
- *1 Reference Value *2 Minimum Guarantee on Measuring Condition: 50kHz,80A/m(sine wave), R.T.

- *1 Hererence Value *2 Millimum Guarantee on Measuring Condition: 50kHz, 1V, 1turn, R.T.
 *4 Typical Value, using a cross section of lead
 *5 Measuring Condition: 100kHz, 80A/m(sine wave), R.T. *6 Tolerance ±0.2[mm]
 *7 Converted from Inductance Value L₁ at 1kHz, 100mA(sine wave), R.T. $\phi c(\mu Wb) = 0.282 \times L_1(\mu H)$

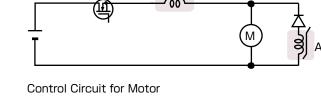
 - t "AMOBEADSTM" sample kits are available. Please ask sales department. t "AMOBEADSTM" and "SPIKE KILLERTM": Registered trademarks of TOSHIBA MATERIALS Co., Ltd. t "AMOBEADSTM" and "SPIKE KILLERTM": Resistered in U.S.A., France, Germany, U.K., Japan.

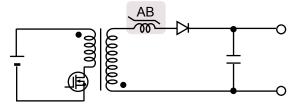
Examples of Applied Circuits and their Characteristics

Application of Amorphous Noise Suppression Devices

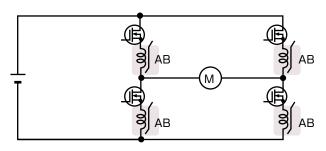


Chopper Converter

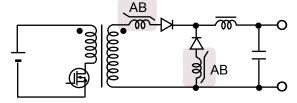




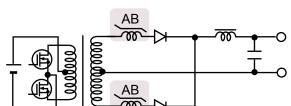
Flyback Converter



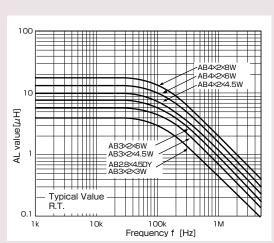
Motor Driving Circuit



Forward Converter

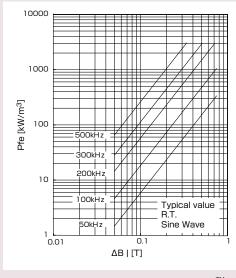


Push-pull Converter

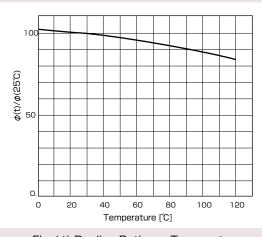


Frequency Characteristics of Inductance

Characteristics (Typical value)



Coreloss Characteristic [AMOBEADS $^{\text{\tiny TM}}$]



 $Flux(\phi)$ Decline Ratio vs. Temperature

Effects of Noise Suppression by AMOBEADSTM

Without Countermeasure AMOBEADS™ "AB4×2×4.5W" Spike Voltage Suppression AU1 AV1 Spike voltage can be reduced Diode Voltage and ringing phenomena can also be prevented by AMOBE-ADS. Also Schottky barrier VD 10V/div diode (SBD) can be protected from over voltage. Frequency:500kHz Diode Current Output Voltage - Current :5V-20A 5A/div AMOBEADS™ "AB4×2×4.5W" RC Snubber +Ferrite Beads **Output Noise Reduction** 67.0m When the ferrite is replaced by AMOBEADS at the secondary output diode (FRD) of the forward converter circuit, the output noise can be tremendously reduced, not only the noise peak level but also the **Output Noise** amplitude range. VN 20mv/div Frequency:150kHz Output Voltage - Current :15V-10A 2#8 Ferrite Beads 4×2×4 AMOBEADS™ "AB4×2×4.5W" ە.90° Primary Surge Voltage MOS-FET Drain-Source Voltage When the ferrite is replaced by AMOBEADS at the secondary output diode (SBD) of the forward converter circuit, the Vns output noise and harmful influence to the primary stage 200V/div can be reduced. These effects are based on the inclination of the actual BH 1,45 1 HS curves between amorphous and ferrite materials. ∆V1 140m 87mV Frequency:250kHz Output Voltage - Current :5V-15A **Output Noise** ٧N **Output Noise** 50mv/div В Actual BH Curve BH characteristics of Ferrite BH characteristics of Amobeads

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